SN54HCT74, SN74HCT74 DUAL D-TYPE POSITIVE-EDGE-TRIGGERED FLIP-FLOPS WITH CLEAR AND PRESET

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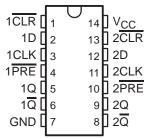
- Inputs Are TTL-Voltage Compatible
- Package Options Include Plastic Small-Outline (D), Thin Shrink
 Small-Outline (PW), and Ceramic Flat (W)
 Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J)
 300-mil DIPs

description

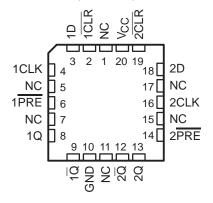
The 'HCT74 contain two independent D-type positive-edge-triggered flip-flops. A low level at the preset (PRE) or clear (CLR) inputs sets or resets the outputs regardless of the levels of the other inputs. When PRE and CLR are inactive (high), data at the data (D) input meeting the setup time requirements are transferred to the outputs on the positive-going edge of the clock (CLK) pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of CLK. Following the hold-time interval, data at the D input may be changed without affecting the levels at the outputs.

The SN54HCT74 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74HCT74 is characterized for operation from -40°C to 85°C.

SN54HCT74 . . . J OR W PACKAGE SN74HCT74 . . . D, N, OR PW PACKAGE (TOP VIEW)



SN54HCT74 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

FUNCTION TABLE

	INP	UTS		OUT	PUT
PRE	CLR	CLK	D	Q	Q
L	Н	Х	Χ	Н	L
Н	L	X	Χ	L	Н
L	L	X	Χ	н†	H [†]
Н	Н	1	Н	Н	L
Н	Н	1	L	L	Н
Н	Н	L	Х	Q_0	Q_0

[†] This configuration is unstable; that is, it does not persist when PRE or CLR returns to its inactive (high) level.



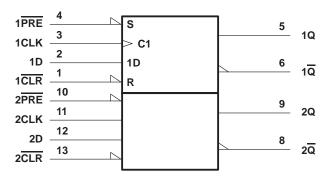
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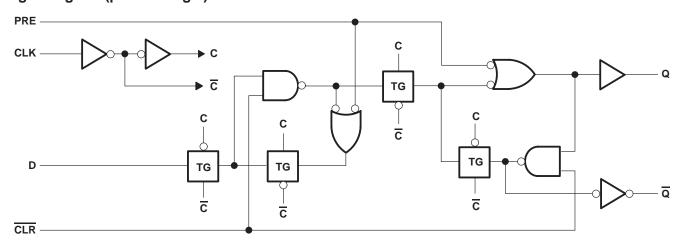
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logic symbol[†]



 $[\]dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, J, N, PW, and W packages.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range‡

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input clamp current, $I_{ K }(V_1 < 0 \text{ or } V_1 > V_{CC})$ (see Note 1)	±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC}) (see Note 1)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): D package	127°C/W
N package	78°C/W
PW package	170°C/W
Storage temperature range, T _{stg} –65	5°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

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recommended operating conditions

			SI	SN54HCT74		SN74HCT74			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	V _{CC} = 4.5 V to 5.5 V	2	, i	15	2			V
V _{IL}	Low-level input voltage	V _{CC} = 4.5 V to 5.5 V	0	PE.	0.8	0		0.8	V
VI	Input voltage		0	7	VCC	0		VCC	V
Vo	Output voltage		0	5	VCC	0		VCC	V
t _t	Input transition (rise and fall) time		00	7	500	0		500	ns
TA	Operating free-air temperature		-55		125	-40		85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		Vaa	T _A = 25°C			SN54HCT74		SN74HCT74		UNIT
PARAMETER			vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
Vall	\/ı = \/ or \/	I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		V
VOH	VI = VIH or VIL	$I_{OH} = -4 \text{ mA}$	4.5 V	3.98	4.3		3.7	7	3.84		
V	\\.\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	I _{OL} = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
VOL	VI = VIH or VIL	I _{OL} = 4 mA	4.5 V		0.17	0.26		0.4		0.33	ľ
lj	VI = VCC or 0		5.5 V		±0.1	±100	7	±1000		±1000	nA
Icc	$V_I = V_{CC}$ or 0,	IO = 0	5.5 V			4	2	80		40	μΑ
∆l _{CC} †	One input at 0.5 V of Other inputs at 0 or	,	5.5 V		1.4	2.4	PAO.	3		2.9	mA
C _i			4.5 V to 5.5 V		3	10		10		10	pF

[†] This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or VCC.

timing requirements over recommended operating free-air temperature range (unless otherwise noted)

			V	T _A =	25°C	SN54H	ICT74	SN74H	ICT74	UNIT
			vcc	MIN	MAX	MIN	MAX	MIN	MAX	UNII
(Object (comment)			4.5 V	0	27	0	18	0	22	MHz
Iclock	clock Clock frequency		5.5 V	0	30	0	20	0	24	IVITIZ
A Pulsa divistian	DDE or OLD law	4.5 V	16		24	7	20			
	PRE or CLR low	5.5 V	14		21	151	18			
'W	t _W Pulse duration	CLK high or low	4.5 V	18		27	EL	23		ns
			5.5 V	16		24	Q	21		
		Data	4.5 V	12		1.8		15		ns
۱.	Setup time before CLK↑		5.5 V	11		16		14		
^l su	t _{su} Setup time before CLKT	PRE or CLR inactive	4.5 V	0		& 0		0		
			5.5 V	0		0		0		
4.	Upld time data ofter CLV↑		4.5 V	0		0		0		
t _h	Hold time, data after CLK↑		5.5 V	0		0		0		ns

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switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	Vaa	T,	λ = 25°C	;	SN54H	ICT74	SN74H	CT74	UNIT
TANAMETER	(INPUT)		(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX
f			4.5 V	27	40		18	_	22		MHz
f _{max}			5.5 V	30	46		20	151	24		IVII IZ
		Q or $\overline{\mathbb{Q}}$	4.5 V		21	35		53		44	
	PRE or CLR		5.5 V		17	31		48		40	no
^t pd	CLK	0 5	4.5 V		20	28	0	42		35	ns
	CLK	Q or $\overline{\mathbb{Q}}$	5.5 V		18	25	g	38		31	
,		Q or $\overline{\mathbb{Q}}$	4.5 V		8	15	0	22		19	no
t _t		QOIQ	5.5 V		7	14		20		17	ns

operating characteristics, T_A = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per flip-flop	No load	35	pF

PARAMETER MEASUREMENT INFORMATION 3 V From Output Test **High-Level** 1.3 V **Under Test** 1.3 V **Point Pulse** n v $C_L = 50 pF$ (see Note A) 3 V Low-Level **Pulse LOAD CIRCUIT** 0 V **VOLTAGE WAVEFORMS PULSE DURATIONS** Input 1.3 V 1.3 V 0 V **tPLH tPHL** 3 V V_{OH} Reference In-Phase 90% 90% 1.3 V Output Input 10% n v tsu - tpHL tpi H Out-of-VOH Data 2.7 V 90% 90% **Phase** Input 10% Output v_{OL} **VOLTAGE WAVEFORMS VOLTAGE WAVEFORMS**

NOTES: A. C_I includes probe and test-fixture capacitance.

B. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r = 6 ns, t_f = 6 ns.

SETUP AND HOLD AND INPUT RISE AND FALL TIMES

C. For clock inputs, f_{max} is measured when the input duty cycle is 50%.

PROPAGATION DELAY AND OUTPUT RISE AND FALL TIMES

- D. The outputs are measured one at a time with one input transition per measurement.
- E. tpLH and tpHL are the same as tpd.



Figure 1. Load Circuit and Voltage Waveforms

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